









AFE7700

SLOSE44A - OCTOBER 2019-REVISED MARCH 2020

AFE7700 Quad-Channel General Purpose RF Transceiver

1 Features

- Quad transmitters based on direct up-conversion architecture:
 - Up to 600 MHz of RF transmitted bandwidth per chain
- Quad receivers based on 0-IF down-conversion architecture:
 - Up to 200 MHz of RF received bandwidth per chain
- Feedback chain based on RF sampling ADC:
 - Up to 600 MHz of RF received bandwidth
- RF frequency range: 600 MHz to 6 GHz
- Four wideband fractional-N PLL, VCO for TX and RX LO
- Dedicated integer-N PLL, VCO for data converters clock generation
- JESD204B and JESD204C SerDes interface support:
 - 8 SerDes transceivers up to 29.5 Gbps
 - 8b/10b and 64b/66b encoding
 - 16-bit, 12-bit, 24-bit and 32-bit formatting
 - Subclass 1 multi-device synchronization
- Package: 17-mm x 17-mm FCBGA, 0.8-mm pitch

2 Applications

- Phased Array Radar
- Defense Radio
- Wireless Communications Test
- Vector Signal Transceiver (VST)
- Electronic Warfare

3 Description

The AFE7700 device is a high-performance, multichannel transceiver, integrating four direct upconversion transmitter chains, four direct down-conversion receiver chains, and two wideband RF sampling digitizing auxiliary chains (feedback paths). The high dynamic range of the transmitter and receiver chains enables high performance wireless transceiver systems.

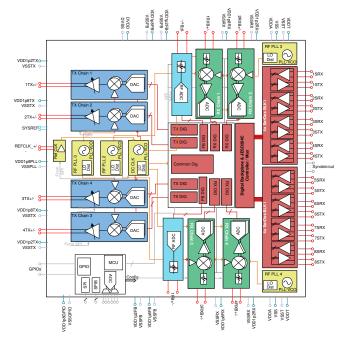
The low power dissipation and large channel integration of the AFE7700 allows the device to address the power and size constraints of multi-antenna and phased array systems. The wideband and high dynamic range feedback path can assist the Digital Pre-Distortion (DPD) of power amplifiers and IQ correction in the transmitter chain. The fast SerDes speed can reduce the number of lanes required to transfer the data in and out.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)				
AFE7700	FCBGA (400)	17.00 mm × 17.00 mm				

For all available packages, see the orderable addendum at the end of the data sheet.

AFE7700 Block Diagram





4 Description (continued)

Each receiver chain of the AFE7700 includes a 28-dB range digital step attenuator (DSA), followed by a wideband passive IQ demodulator, and a baseband amplifier with integrated programmable antialiasing low pass filters, driving a continuous-time sigma-delta ADC. The RX chain can receive an instantaneous bandwidth (IBW) up to 200 MHz. Each receiver channel has two analog peak power detectors and various digital power detectors to assist an external or internal autonomous AGC control for receiver channels, and a RF overload detector for device reliability protection. The integrated QMC (quadrature mismatch compensation) algorithm is capable to continuously monitor and correct for the RX chain I and Q imbalance mismatch without the need to inject any specific signals or perform offline calibration.

Each transmitter chain includes two 14-bit, 3-Gsps IQ DACs, followed by a programmable reconstruction and DAC image rejection filter, an IQ modulator driving a wideband RF amplifier with 39-dB range gain control. The TX chain integrated QMC and LO leakage cancellation algorithms, leveraging the FB path can constantly track and correct for the TX chain IQ mismatch and LO leakage.

Each FB path is based on RF sampling architecture, and includes an input RF DSA driving a 14-bit, 3-Gsps RF ADC. The direct sampling architecture provides an inherently wideband receiver chain and simplifies the calibration of the TX chains impairments. The FB path integrates two independent NCO that allows a fast switching between two observed RF input bands.

The synthesizer section integrates four fractional-N RF PLL that can generate four different RF LO, allowing the device to support up to two different bands, each one configured as two transmitters, two receivers and one feedback paths.

5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (October 2019) to Revision A

Page

Product Folder Links: AFE7700



6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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6.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

6.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: AFE7700

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www.ti.com 30-Sep-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
AFE7700IABJ	ACTIVE	FCBGA	ABJ	400	90	RoHS & Green	SNAGCU	Level-3-260C-168 HR	-40 to 85	AFE7700	Samples
AFE7700IALK	ACTIVE	FCBGA	ALK	400	90	Non-RoHS & Green	Call TI	Level-3-220C-168 HR	-40 to 85	AFE7700 SNPB	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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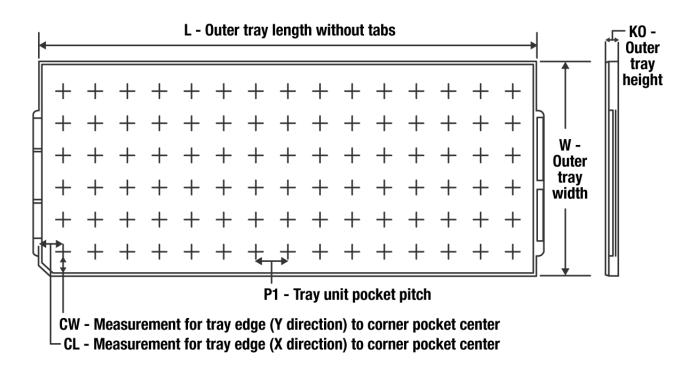
PACKAGE OPTION ADDENDUM

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TRAY

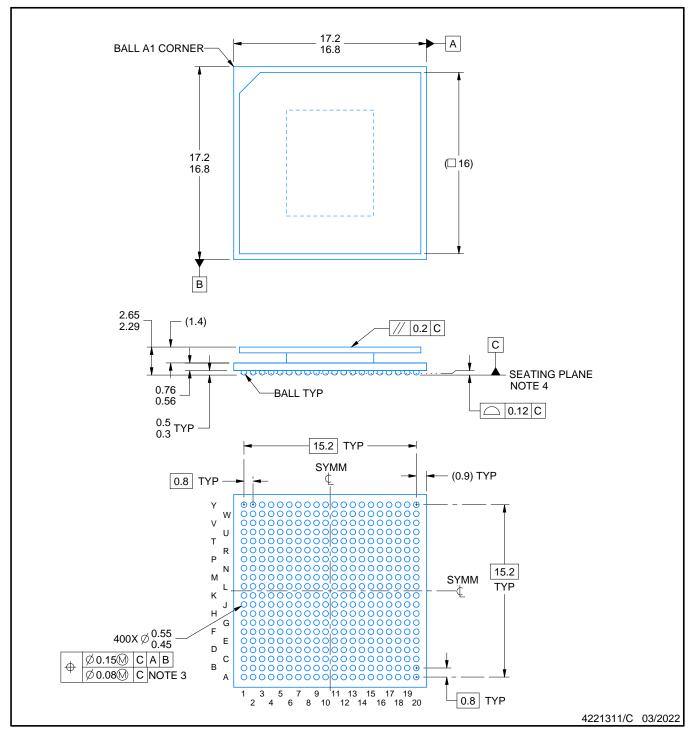


Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	Κ0 (μm)	P1 (mm)	CL (mm)	CW (mm)
AFE7700IABJ	ABJ	FCBGA	400	90	6 x 16	150	315	135.9	7620	19.5	21	19.2
AFE7700IALK	ALK	FCBGA	400	90	6 x 16	150	315	135.9	7620	19.5	21	19.2



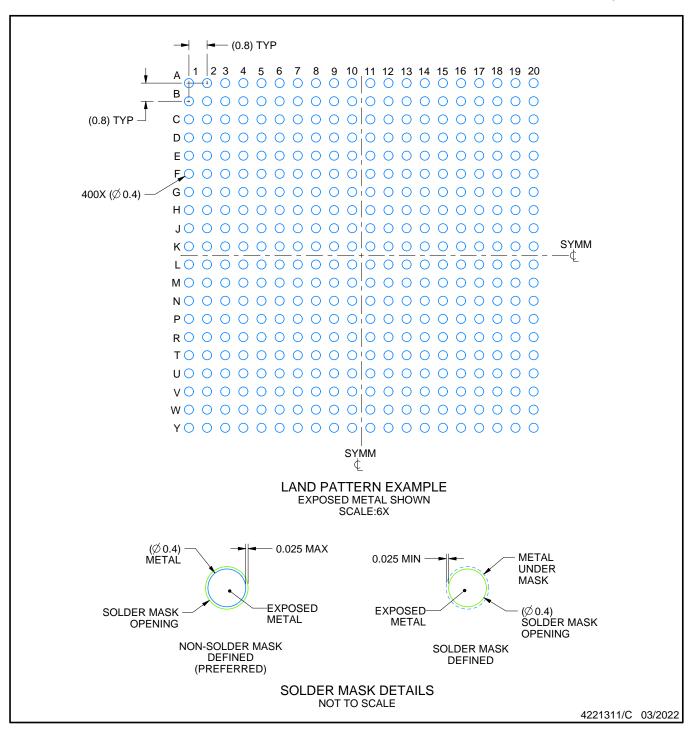


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
- 4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.

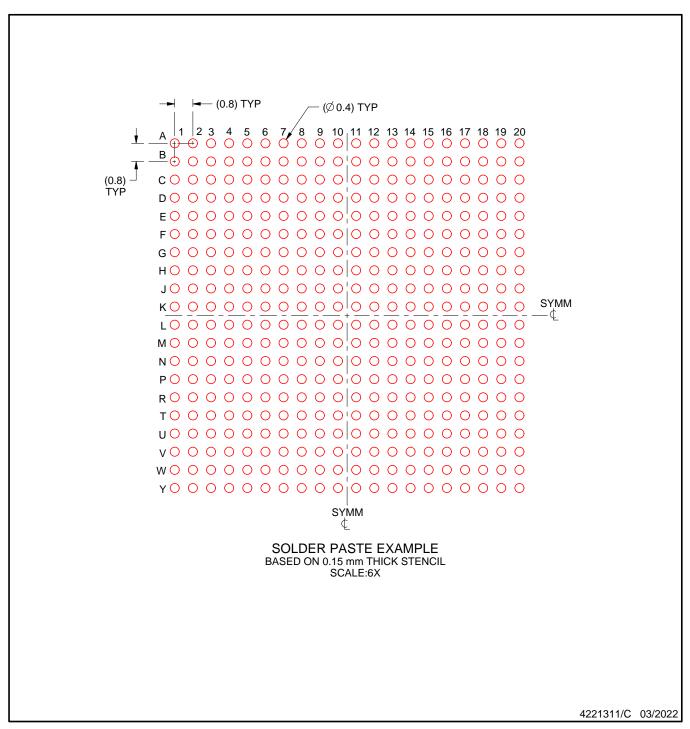




NOTES: (continued)

Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.For more information, see Texas Instruments literature number SPRU811 (www.ti.com/lit/spru811).



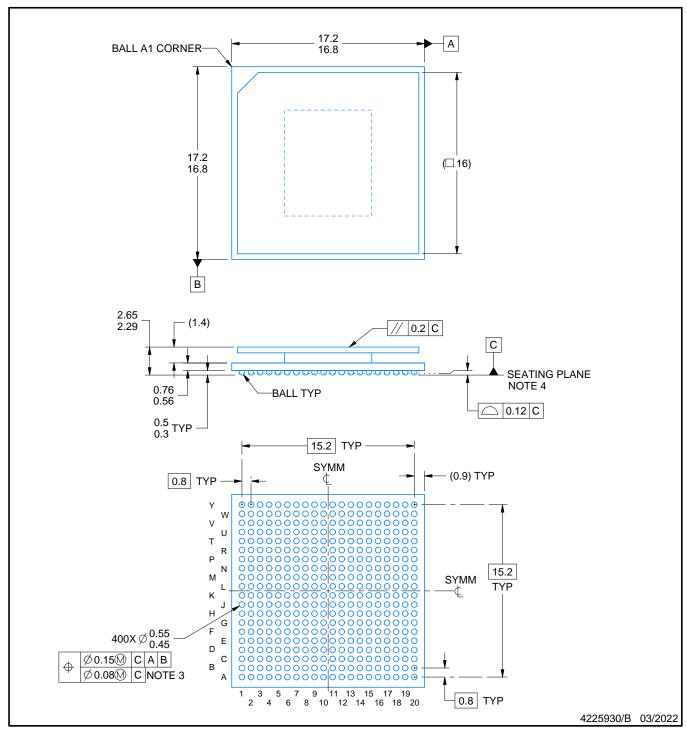


NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



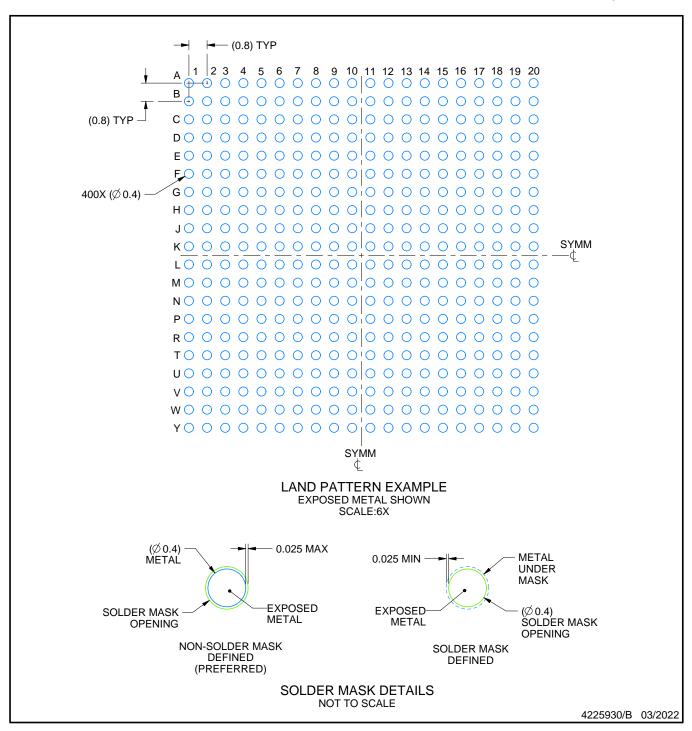




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- 2. This drawing is subject to change without notice.
- 3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
- 4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
- 5. Pb-Free die bump and SnPb solder ball.

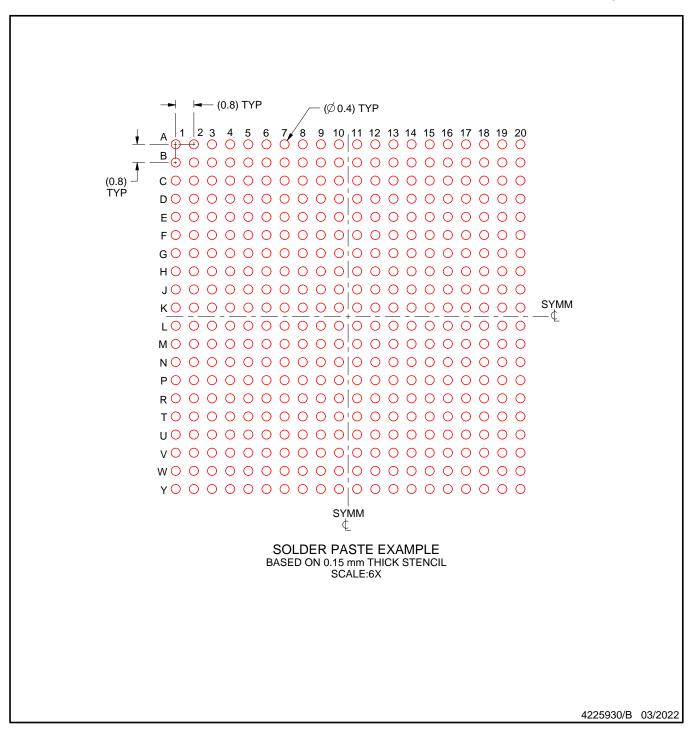




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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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